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# HR-TEM and FIB-SEM characterization of formation of eutectic-like structure from amorphous GdAlO<sub>3</sub>-Al<sub>2</sub>O<sub>3</sub> system

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**Abstract:** The crystallization process of the eutectic composition of  $GdAlO_3-Al_2O_3$  from the amorphous phase prepared by rapid-quenching of melt that leads to the formation of a cantaloupe skin-like microstructure was investigated using focused ion-beam scanning electron microscopy (FIB-SEM) and high-resolution transmission electron microscopy (HR-TEM). The amorphous films were heat-treated at temperatures between 1000 °C and 1500 °C for up to 30 min to form the eutectic phases of GdAlO<sub>3</sub> and  $Al_2O_3$ . The GdAlO<sub>3</sub> and  $Al_2O_3$  crystal phases that formed from the amorphous phase were identified by FIB-SEM and HR-TEM. Both components began to crystallize and grow from the amorphous phase separately at different temperatures. The formation process of these crystal phases was different from that of the ordinary eutectic microstructure solidified from the GdAlO<sub>3</sub>–Al<sub>2</sub>O<sub>3</sub> system. Therefore, the observed structure is termed "eutectic-like" for distinction. The microstructures formed from the amorphous phases at sufficiently high temperatures consisted of ultra-fine microstructures of individually crystallized components and were similar to ordinary eutectic microstructures. By heat-treating the amorphous films at 1500 °C for either 2 min, 8 min or 30 min, the ultra-fine components of GdAlO<sub>3</sub> and Al<sub>2</sub>O<sub>3</sub> were found to crystallize following a eutectic-like stage after 8 min of heat treatment. **Key words:** eutectic; amorphous; GdAlO<sub>3</sub>–Al<sub>2</sub>O<sub>3</sub>; eutectic-like; HR-TEM; FIB-SEM; Crystallization

# **1** Introduction

One solution for realizing the higher operating temperatures of the next-generation turbo-blades operating at gas temperatures as high as 1600 °C is by way of an in-situ development of oxide-based ceramic composites by directed solidification of melt having a eutectic composition. The resulting structure is a single-crystal, three-dimensional lattice with no grain boundary, i.e., a material with coherent interfaces and no vitreous phase.

This material is known to exhibit a mechanical strength that is nearly constant up to the melting temperature unlike polycrystalline ceramics that gradually looses strength with temperature. It is also known that the rupture stress in this material can be increased by reducing the size of the constituent phases without reducing the creep strength. This is the case of perovskite-structured oxides having a high temperature plasticity in a eutectic system (melting at 1700–1900 °C)

that combines alumina with a rare earth oxide having either a perovskite (XAlO<sub>3</sub>; X: Gd, Eu) or a garnet (Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub>; Y: Er, Dy, Yb) structure. Recently, eutectic ceramics have been considered to be a candidate not only as a heat-resistant material but also as a functional material in various other applications, such as thermophotovoltaic (TPV) generation [1–3] and porous materials technology [4–6].

Although the formation process of the ordinary eutectic microstructures by cooling the eutectic melts has been well-known, the formation process of the eutectic-like microstructures from an amorphous phase has not so far been elucidated in our previous work [7,8].

The current study focuses on the focused ion-beam scanning electron microscopy (FIB-SEM) and high-resolution transmission electron microscopy (HR-TEM) characterization of the crystallization process of the  $GdAlO_3-Al_2O_3$  binary eutectic system [9–12]. We characterized the ultra-fine eutectic microstructure processed both from the eutectic melt and from the amorphous phase.

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## 2 Experimental

### 2.1 Sample preparation

The raw materials were the powders of  $Al_2O_3$  (99%, Kanto Chemical, Japan) and  $Gd_2O_3$  (99.95%, Kanto Chemical, Japan). The powders in the eutectic composition 23% (mole fraction) of  $Gd_2O_3$  and 77% (mole fraction)  $Al_2O_3$  were processed using a mortar and pestle in a 3% (mass fraction) polyvinyl alcohol (Waco Pure Chemical Industries, Japan; degree of polymerization: ~500) solution. The mixture was pressed into a rod-shaped compact and was calcined at 1300 °C for 1 h.

The top of the sintered rod was melted by arc discharge; the slow-cooled samples of solid eutectic composite were produced after turning off the discharge. The sample was rapidly cooled by quenching the droplet between rotating aluminum rollers to form an amorphous film. The amorphous films were obtained from heating between 1000 °C and 1600 °C for 30 min to form a eutectic phase of GdAlO<sub>3</sub> and Al<sub>2</sub>O<sub>3</sub>. The films were heated at 1500 °C for various periods ranging from 30 s to 30 min for the investigation of the crystallization process of the ultra-fine microstructures in the eutectic-like composite of GdAlO<sub>3</sub> and Al<sub>2</sub>O<sub>3</sub>.

# 2.2 Specimen preparation and characterization by FIB-SEM and HR-TEM

For the FIB-SEM analysis, a SEIKO FIB/SEM Hybrid System SMI 3050SE was operated with the acceleration voltage of 30 kV, the beam current of 90 pA, and the beam size of 22 nm. An H-bar and lift-out technique was employed to prepare the TEM specimens by FIB milling. For all the specimens, the acceleration voltage of 30 kV and the beam current of 90 pA were applied. The TEM was a JEOL JEM–2100F and was operated at 200 kV at a point resolution 0.19 nm for the high resolution characterization.

### **3 Results and discussion**

Figure 1 shows the HR-TEM analysis of a rapidly quenched specimen and heat-treated specimens of the  $Gd_2O_3$ -Al<sub>2</sub>O<sub>3</sub> eutectic composition, sintered at 1000 °C for 30 min. The rapidly quenched specimen was found to be mostly amorphous, as shown in Fig. 1, establishing that an amorphous film can be successfully prepared by rapidly quenching the  $Gd_2O_3$ -Al<sub>2</sub>O<sub>3</sub> eutectic melt.

The HR-TEM analysis of the lattice image of the eutectic  $23\%Gd_2O_3$ -77%Al<sub>2</sub>O<sub>3</sub> after being sintered at 1000 °C for 30 min reveals a mixed phase of a crystalline region (dark) and a noncrystalline region (bright), as shown in Fig. 1. The dark, crystalline regions exhibit

lattices, as indicated by A. The bright, noncrystalline regions have no order in atomic arrangement, as indicated by B.



Fig. 1 HR-TEM analysis of lattice image of eutectic 23%Gd<sub>2</sub>O<sub>3</sub>-77%Al<sub>2</sub>O<sub>3</sub> sintered at 1000 °C for 30 min

A low magnification image of the region analyzed by EDS is shown in Fig. 2(a) and the qualitative data for the region are shown in Fig. 2(b) with the peaks for  $GdAlO_3$  identified.

For the specimen sintered at 1300 °C for 30 s, dark and bright regions coexist in the TEM image at a low magnification, as shown in Fig. 3(a), in which the dark region is the crystalline  $Al_2O_3$  and the bright region is the crystalline GdAlO<sub>3</sub>. A high magnification image of GdAlO<sub>3</sub> from a bright area is shown in Fig. 3(b), and a high magnification image of  $Al_2O_3$  from a dark area is shown in Fig. 3(c).

The dark areas  $(Al_2O_3)$  and the bright areas  $(GdAlO_3)$  appear to be in an initial or intermediate stage of crystallization, which is confirmed by the TEM analysis of the sample sintered at 1300 °C for 30 s, as shown Fig. 4.

In Figs. 5–7, the eutectic composites sintered at 1500 °C for 2 min, 8 min, or 30 min are compared with the crystalline  $Al_2O_3$  appearing dark and the crystalline GdAlO<sub>3</sub> appearing bright, analyzed earlier by FIB-SEM and HR-TEM.

In Fig. 5, the bright area is GdAlO<sub>3</sub> and the dark area is Al<sub>2</sub>O<sub>3</sub>. Most of the Al<sub>2</sub>O<sub>3</sub> component is crystallized from the amorphous phase along with GdAlO<sub>3</sub> after a heat treatment at 1500 °C for 2 min, as shown in Fig. 5, which can be explained well, based on the previous results by KAKEGAWA et al [13]. The completely crystallized components appeared after a heat treatment of 8 min, as shown in Fig. 6. A similar crystallized microstructure is present in the sample sintered for 30 min according to the FIB-SEM micrographs that



Fig. 2 Region analyzed by EDS (a) and qualitative data with peaks for GdAlO<sub>3</sub> identified (b)



show apparently fine, eutectic-like microstructures. These microstructures having an appearance of a cantaloupe skin are intertwined GdAlO<sub>3</sub> and Al<sub>2</sub>O<sub>3</sub> crystals, as confirmed by the TEM analysis presented in Fig. 7. It is confirmed that the crystallization process of  $Gd_2O_3$ -Al<sub>2</sub>O<sub>3</sub> completes after being sintered at 1500 °C for 8 min.

The formation process of eutectic-like microstructures

from the amorphous phase is presumably different from that of an ordinary eutectic microstructure, as mentioned in Refs. [7,8]. In general, an ordinary eutectic microstructure is formed by simultaneously crystallizing individual components at a eutectic temperature. In contrast, the crystallization and the growth of the GdAlO<sub>3</sub> and Al<sub>2</sub>O<sub>3</sub> components from the amorphous phase begin separately at different heating temperatures. In the case of



Fig. 4 TEM analysis of sample sintered at 1300 °C for 30 s

low temperatures, in which the Al<sub>2</sub>O<sub>3</sub> component cannot crystallize, the microstructure consists of round-shaped GdAlO<sub>3</sub> crystals and the amorphous Al<sub>2</sub>O<sub>3</sub> phase, as proved by KAKEGAWA et al [13].

When one component nucleates and grows, the component is consumed during the crystallization and its concentration is lowered. As a result, the crystal growth slows down. However, there is a directional fluctuation in the crystal growth [14,15]. If the growth occurs on a convex part of the crystal, the concentration of its component in the surrounding region increases and the crystal can grow further. In addition, the crystal growth while releasing the latent heat and enhancing the growth. In this mechanism, the crystal will not grow into a sphere but into a long and thin shape. There is also a directional fluctuation of the component in the amorphous phase that

TEM image



**Fig. 5** FIB-SEM and HR-TEM microstructures of eutectic composites sintered at 1500 °C for 2 min (Crystalline Al<sub>2</sub>O<sub>3</sub> appears dark and crystalline GdAlO<sub>3</sub> appears bright)

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Fig. 6 FIB-SEM and HR-TEM microstructures of eutectic composites sintered at 1500 °C for 8 min (Crystalline Al<sub>2</sub>O<sub>3</sub> appears dark and crystalline GdAlO<sub>3</sub> appears bright)



Fig. 7 FIB-SEM and HR-TEM microstructures of eutectic composites sintered at 1500 °C for 30 min (Crystalline Al<sub>2</sub>O<sub>3</sub> appears dark and crystalline GdAlO<sub>3</sub> appears bright)

makes the long thin crystals to intertwine when they meet. GAP crystallizes in this way first and then  $Al_2O_3$  crystallizes later.

The above explains why the observed microstructure is different from an ordinary eutectic microstructure. The fine, eutectic-like microstructure cannot materialize from the crystallization of a single component. As the heating temperature reaches an appropriate temperature, the  $Al_2O_3$  component can crystallize along with the remaining amorphous  $Al_2O_3$  phase. When heat treated at 1500 °C, the  $Al_2O_3$  component begins to crystallize immediately along with the GdAlO<sub>3</sub> component and forms a fine eutectic-like microstructure with a cantaloupe skin appearance, as shown in Fig. 5.

### **4** Conclusions

An ultra-fine microstructure of GdAlO<sub>3</sub> and Al<sub>2</sub>O<sub>3</sub> is formed from the amorphous phase following an eutectic-like stage by simultaneously crystallizing both the components at a sufficiently high temperature of 1500 °C for 8 min. The eutectic-like microstructure formed from the amorphous phase is very fine in texture compared with an ordinary eutectic microstructure.

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